

DATASHEET

ITR20002

Features

- Fast response time
- High analytic
- Cut-off visible wavelength λp=840nm
- · High sensitivity
- Pb free
- This product itself will remain within RoHS compliant version
- •Compliance with EU REACH
- •Compliance Halogen Free.(Br < 900ppm, Cl < 900ppm, Br+ Cl < 1500ppm)

Description

• The ITR20002 consist of an infrared emitting diode and an NPN silicon phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing. The phototransistor receives radiation from the IR only . This is the normal situation. But when an object is in between . phototransistor could not receive radiation

Applications

- Mouse Copier
- Floppy disk driver
- Non-contact Switching
- For Direct PC Board



Device Selection Guide

Device No.	Chip Materials	Lens Color
IR	GaAlAs	Water clear
PT	Silicon	Water clear

Absolute Maximum Ratings (Ta=25 $^{\circ}$ C)

Parameter		Symbol	Ratings	Unit
	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	100	mW
input	Reverse Voltage	V_R	5	V
	Forward Current	l _F	60	mA
	Peak Forward Current (*1) Pulse width ≦100µs, Duty cycle=1%	I _{FP}	1	А
Output	Collector Power Dissipation	Pc	80	mW
	Collector Current	I _C	20	mA
	Collector-Emitter Voltage	B V _{CEO}	35	V
	Emitter-Collector Voltage	B V_{ECO}	6	V
Operating Temperature		Topr	-25~+85	$^{\circ}\mathbb{C}$
Storage Temperature		Tstg	-40~+85	$^{\circ}\mathbb{C}$
Lead Soldering Temperature (*2) (1/16 inch form body for 5 seconds)		Tsol	260	$^{\circ}\! \mathbb{C}$

^(*1) $tw=100 \mu sec.$, T=10 msec. (*2) t=5 Sec



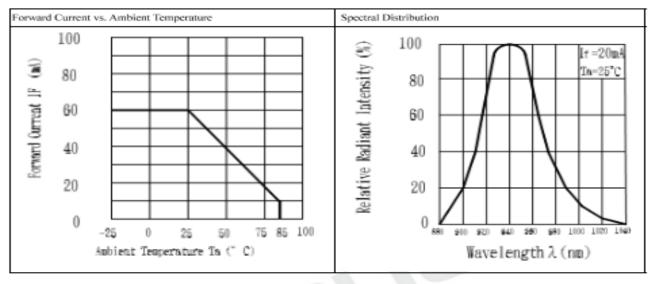
Electro-Optical Characteristics (Ta=25℃)

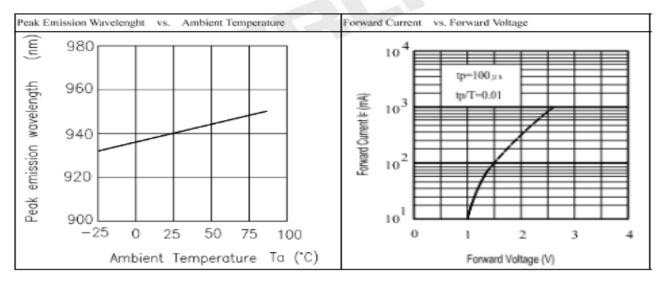
Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input	Forward Voltage	V_{F}		1.2	1.5	>	I _F =20mA	
	Reverse Current	I _R			10	μΑ	V _R =5V	
	Peak Wavelength	λ_{P}		940		nm	I _F =20mA	
Output	Dark C urrent	I _{CEO}			100	nA	V _{CE} =20V,Ee=0mW/cm ²	
	C-E Saturation Voltage	V _{CE} (sat)			0.4	V	I _C =0.04mA IF=40mA	
Transfer Characteristics	Collect Current	I _C (ON)	0.04		0.9	mA	VCE=5V IF=20mA	
	Rise time	t _r		20		µsec	V_{CE} =2V, I_{C} =100uA , R_{L} =100 Ω	
	Fall time	t _f		25		µsec		

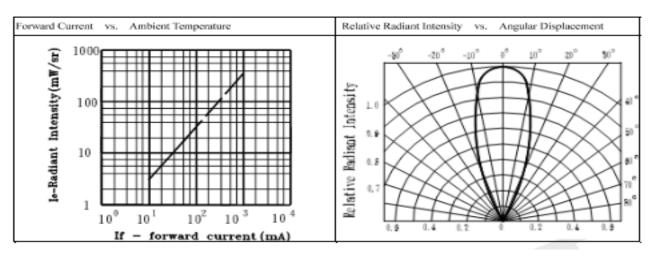
IC(on) at the testing condition—with reflector in 5mm away



Typical Electrical/Optical/Characteristics Curves for IR

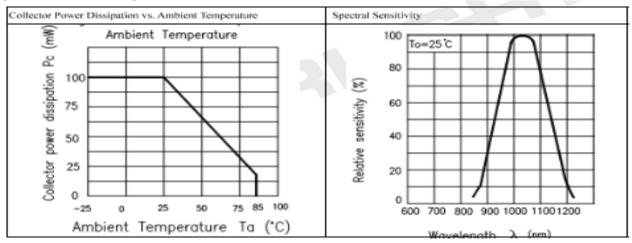


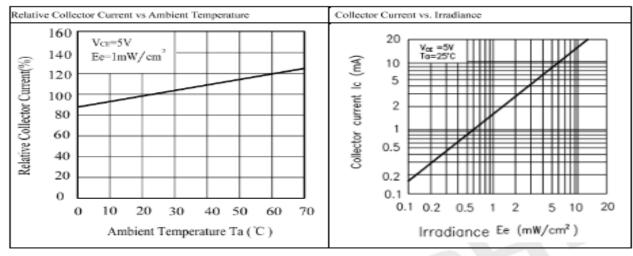


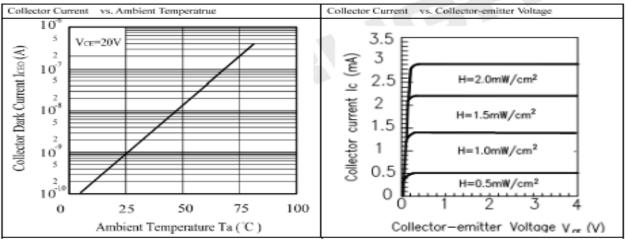




Typical Electrical/Optical/Characteristics Curves for PT

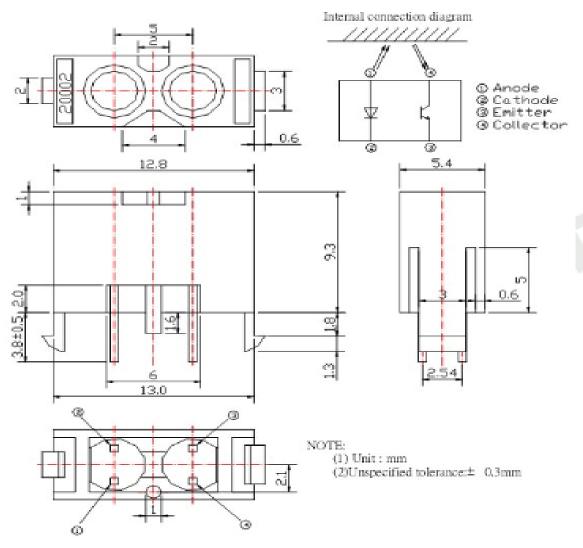








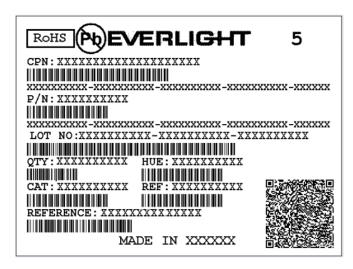
Package Dimension



Note: Tolerances unless dimensions ±0.25mm



Label Form Specification



- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- · CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- · LOT No: Lot Number
- X: Month
- · Reference: Identify Label Number

Packing Quantity Specification

1.150PCS/1Bag,5Bags/1Box

2.10Boxes/1Carton

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- 2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
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